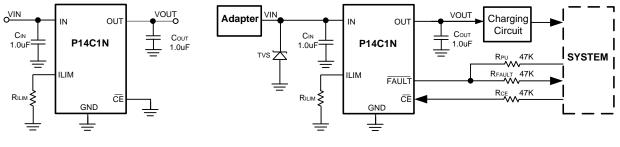


#### Description

The P14C1N is an Over-Voltage-Protection (OVP) load switch with fixed OVLO threshold voltage. The OVLO threshold voltage is fixed 6.0V. The device will switch off internal MOSFET to disconnect IN to OUT to protect load when any of input voltage over the threshold. The Over temperature protection (OTP) function monitors chip temperature to protect the device. The OCP function turns off OUTPUT if the load current is over the threshold and recovers when VIN re-plug or CE reactive. The OCP current limit threshold is adjustable by an external R<sub>ILIM</sub>.

The P14C1N is available in DFN2x2-8L. Standard products are Pb-free and Halogen-free.



Typical Application 1

Typical Application 2

Figure 1: Typical Application

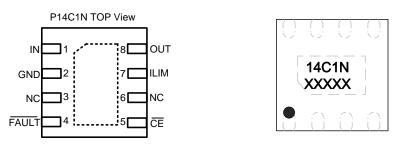


Figure 2: Pin order (Top view) and Marking (Top view)

#### Feature

- Maximum input voltage : 32V
- Ultra fast OVP response time: 50ns (Typ.)
- Fixed OVLO threshold voltage:  $6.0V, \pm 3\%$
- > Adjustable over-current protection: 100mA-1.5A,  $\pm$ 10%
- Supports up to 1.5 A Load Current
- Thermal Shutdown
- Enable Function
- Fault Status Indication
- > Available in Green DFN2x2-8L Package

#### Application

- Mobile Handsets and Tablets
- > Portable Media Players
- Low-Power Handheld Devices

**P14C1N** 



## P14C1N

## **Pin Definitions**

Pin No.	Symbol	Descriptions
1	IN	Switch Input and Device Power Supply.
2	GND	Ground Terminal. Connect to the thermal pad and to the ground rail of the circuit.
3,6	NC	No connect.
4	FAULT	Open-drain Device Status Output. FAULT is pulled to GND with a $3k\Omega$ resistant internally when the input pass FET has been turned off due to input over-voltage or overload current protection, an over-temperature condition, or because the battery voltage is outside safe limits. FAULT is high impedance during normal operation.
5	ĊĒ	Active-Low Chip Enable Input. Connect $\overline{CE}$ = "HIGH" to turn the input pass FET off. Connect $\overline{CE}$ = "LOW" to turn the internal pass FET on, connecting the input to the charging circuitry. CE is internally pulled down.
7	ILIM	Current limit adjustment. Connect a resistor to GND to set over current threshold. $I_{\text{Lim}} = 600/R_{\text{ILIM}}$ . (current in A, resistance in $\Omega$ ) Short ILIM to GND will disable current limitation.
8	OUT	Switch output Terminal to the Charging System.

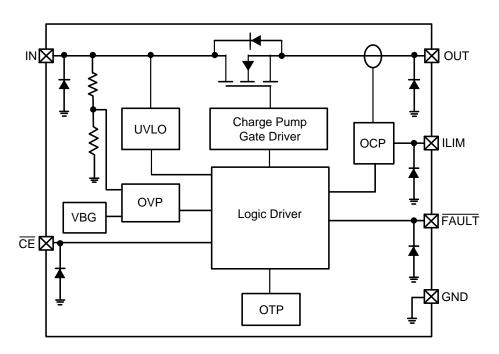


Figure 3: IC Block Diagram



### Absolute maximum rating

Parameter(Note1)	Symbol	Value	Units
Input voltage (IN pin)	V <sub>IN</sub>	-0.3 ~ 32	V
Output voltage (OUT pin)	V <sub>OUT</sub>	-0.3 ~ 6.0	V
Junction temperature	TJ	150	°C
Lead temperature(10s)	TL	260	°C
Storage temperature	Tstg	-55~150	°C
	НВМ	HBM ±2000 V	
ESD Ratings	MM	±500	V

**Note 1:** Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

#### **Recommended Operating Conditions**

Parameter	Symbol	Value	Units
Input voltage	V <sub>IN</sub>	3.5~32	V
MAX Continuous Output current	Ιουτ	1.2	A
Ambient operating temperature	Topr	-40~85	°C



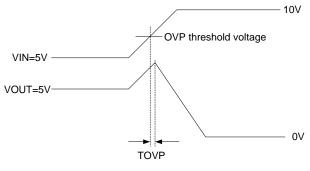
### Over voltage protector

#### **Electrical Characteristics**

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Input voltage range	V <sub>IN</sub>		3.5		32	V
Quiescent current	lα	NO Load, /CE=GND, V <sub>IN</sub> =5V		120	200	uA
Over voltage quiescent current	I <sub>Q_OVP</sub>	NO Load, /CE=GND, V <sub>IN</sub> =30V		200		uA
Disable OVP quiescent current	$I_{Q_{DIS}}$	NO Load, /CE=5.5V, V <sub>IN</sub> =5.5V		50	100	uA
Drop Voltage from IN to OUT	V <sub>DROP</sub>	V <sub>IN</sub> =5V, I <sub>OUT</sub> =0.5A		110	140	mV
OVP response time	t <sub>OVP</sub>	V <sub>IN</sub> rising, C <sub>IN</sub> =C <sub>L</sub> =0pF (Note2)		50		ns
OVP voltage	V <sub>OVLO</sub>	VIN rising	5.82	6.0	6.18	V
/CE high threshold voltage	V <sub>CE_H</sub>	V <sub>CE</sub> Rising	1.4			V
/CE low threshold voltage	$V_{CE_L}$	V <sub>CE</sub> Falling			0.4	V
UVLO threshold voltage	VUVLO	VIN rising		2.35		V
UVLO hysteresis voltage	VUVLO_HYS	VIN falling		25		mV
OCP setting range	IOCP_RANG		100		1500	mA
Debounce Time	TDEB	VIN>UVLO to VOUT=VIN*10%	10	18	30	ms
Turn On Time	TON	VOUT=VIN*10% to VOUT=VIN*90%		40		us
Output discharge resistance	R <sub>DCHG</sub>	VIN=5V		400		Ω
OTP threshold temperature	TOTP	VIN=5V		150		°C
OTP hysteresis temperature	THYS	VIN=5V		20		°C

(T\_A=25  $^\circ\!\!\!\mathrm{C}$  , V\_IN=5V, C\_IN=1.0uF, C\_OUT=1.0uF, unless otherwise specified.)

Note 2: Guaranteed by design



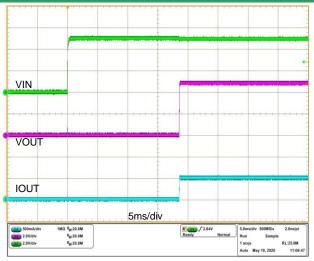
OVP response time test

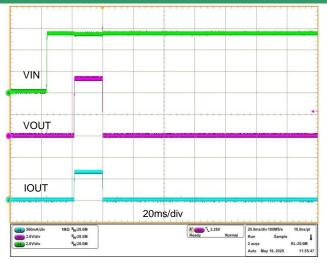
**P14C1N** 



### **P14C1N**

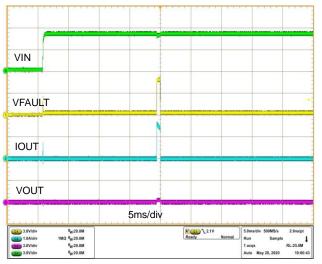




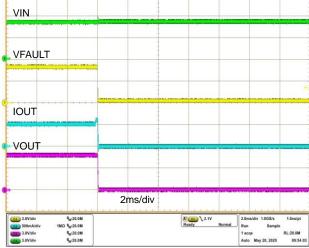


Power on Response(Rout= $10\Omega$ , R<sub>ILIM</sub>= $1k\Omega$ )

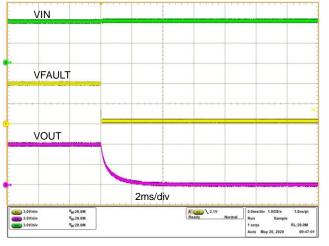
Power on OCP Response(Rout= $8\Omega$ , R<sub>ILIM</sub>= $1k\Omega$ )



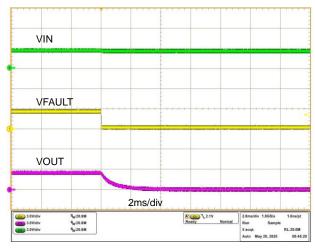
Power on Response with Output Short



**OCP** Response



OVP Response



**UVLO** Response

RL:20.0M 09:54:



#### **Function Descriptions**

# 1. Under-voltage Lockout (UVLO)

The under-voltage lockout (UVLO) circuit disables the power switch until the input voltage reaches the UVLO turn on threshold. Built-in hysteresis prevents unwanted on and off cycling because of input voltage droop during turn on.

# 2. Over Current Protection (OCP)

If the load current rises to the OCP threshold, the device will cut off the output voltage immediately[1]. The OCP threshold is calculated by the equation:  $I_{Lim} = 600/R_{ILIM}$  (current in A, resistance in  $\Omega$ ). Note[1]: It takes 18ms after power on for OCP begins to detect.

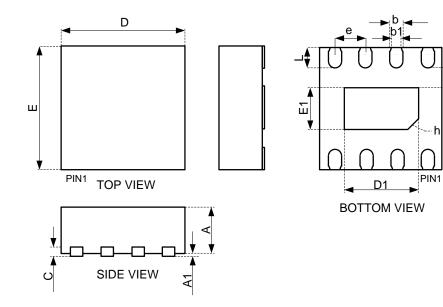
# 3. Over-voltage Lockout (OVLO)

When VIN exceeds the OVP threshold voltage, the over-voltage lockout (OVLO) circuit turns off the protected power switch.



### Over voltage protector

## Product dimension (DFN2X2-8L)



Dim	Millimeters				
Dim	MIN	Тур.	MAX		
А	0.70	0.75	0.80		
A1	0.000	0.020	0.050		
b	0.200	0.250	0.300		
b1	0.18REF				
С	0.180	0.200	0.220		
D	1.900	2.000	2.100		
Е	1.900	2.000	2.100		
D1	1.100	1.200	1.300		
E1	0.600	0.700	0.800		
е	0.475	0.500	0.525		
L	0.300	0.350	0.400		
F	0.280	0.300	0.320		
h	0.230	0.280	0.330		

## P14C1N

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